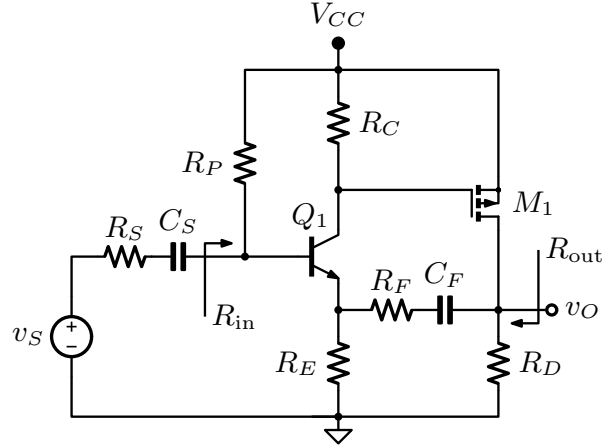


Exercise 1. Parameters at 25 °C:

- $V_{CC} = 12\text{ V}$;
- $R_S = 1\text{ k}\Omega$, $R_P = 1.2\text{ M}\Omega$,
 $R_C = 10\text{ k}\Omega$, $R_E = 220\ \Omega$,
 $R_F = 1.2\text{ k}\Omega$, $R_D = 2.2\text{ k}\Omega$;
- $C_S = 1\ \mu\text{F}$, $C_F = 220\ \mu\text{F}$;
- Q_1 (npn BJT): $V_{BE} = 0.7\text{ V}$,
 $\beta_F = \beta_0 = 100$, $r_o = +\infty$;
- M_1 (e-PMOS): $V_t = -3\text{ V}$,
 $I_{DSS} = 0.3\text{ mA}$, $r_o = +\infty$.



1. Bias point of the devices.

From the leftmost branch of the circuit (the one polarizing Q_1), the KVL gives Q_1 's base current I_B :

$$\begin{aligned} V_{CC} &= R_P I_B + V_{BE} + R_E(\beta_F + 1)I_B \implies \\ \implies I_B &= \frac{V_{CC} - V_{BE}}{R_P + R_E(\beta_F + 1)} = \frac{12\text{ V} - 0.7\text{ V}}{1.2\text{ M}\Omega + 220\ \Omega \cdot 101} \simeq 9.245\ \mu\text{A}, \end{aligned}$$

therefore the collector current is $I_C = \beta_F I_B \simeq 924.5\ \mu\text{A}$.

Since the gate of M_1 drains no current, Q_1 's collector current I_C flows also on the resistor R_C and the KVL on this branch allows to calculate V_{CE} :

$$\begin{aligned} V_{CC} &= R_C \beta_F I_B + V_{CE} + R_E(\beta_F + 1)I_B \implies \\ \implies V_{CE} &= V_{CC} - [R_C \beta_F + R_E(\beta_F + 1)]I_B = \\ &= 12\text{ V} - [10\text{ k}\Omega \cdot 100 + 220\ \Omega \cdot 101] \cdot 9.245\ \mu\text{A} = \\ &\simeq 2.55\text{ V}. \end{aligned}$$

Now, V_{GS} is the voltage across R_C , i. e. $V_{GS} = -R_C I_C \simeq -9.245\text{ V}$, therefore

$$\begin{aligned} I_{DS} &= I_{DSS} \left(1 - \frac{V_{GS}}{V_t}\right)^2 = 0.3\text{ mA} \left(1 - \frac{-9.245\text{ V}}{-3\text{ V}}\right)^2 \simeq 1.300\text{ mA} \\ V_{DS} &= -(V_{CC} - R_D I_{DS}) = -12\text{ V} + 2.2\text{ k}\Omega \cdot 1.300\text{ mA} \simeq -9.14\text{ V}. \end{aligned}$$

Therefore, the operating points are $Q_1(924.5\ \mu\text{A}, 2.55\text{ V})$ and $M_1(1.300\text{ mA}, -9.14\text{ V})$.

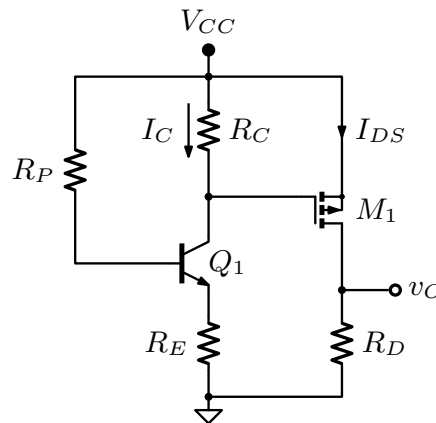


Figure 1: Bias point analysis of the circuit.

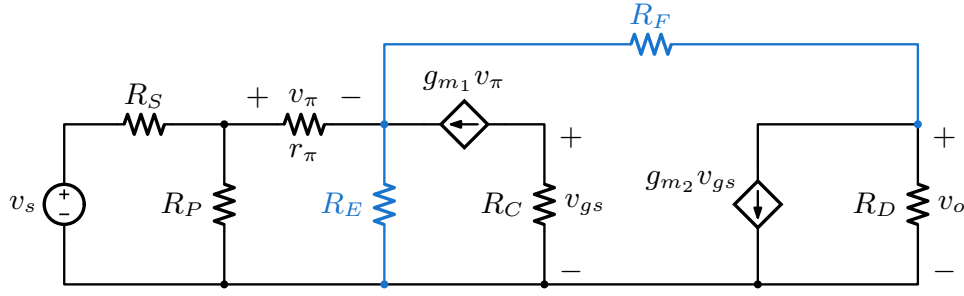


Figure 2: Small signal model of the circuit, where the feedback network is highlighted in blue.

2. *Equivalent small signal circuit, according to feedback theory.*

From the operating points of the two transistor, the small signal parameters are:

$$g_{m1} = \frac{I_C}{V_T} = \frac{924.5 \mu\text{A}}{26 \text{ mV}} \simeq 35.6 \text{ mS}, \quad r_{\pi} = \frac{\beta_0}{g_{m1}} = \frac{100}{35.6 \text{ mS}} \simeq 2812 \Omega$$

$$g_{m2} = \frac{2}{|V_t|} \sqrt{I_{DSS} I_{DS}} = \frac{2}{3 \text{ V}} \sqrt{0.3 \text{ mA} \cdot 1.300 \text{ mA}} \simeq 416 \mu\text{S}.$$

Since the amplifier uses voltage sampling and voltage mixing, the equivalent β -network model is pictured in Figure 3, where

$$\begin{cases} v_1 = \beta v_2 + R_{11} i_1 \\ i_2 = \frac{v_2}{R_{22}} + \delta i_1 \end{cases} \implies \beta \triangleq \left. \frac{v_1}{v_2} \right|_{i_1=0} = \frac{R_E}{R_F + R_E} \simeq 0.155$$

$$R_{11} \triangleq \left. \frac{v_1}{i_1} \right|_{v_2=0} = R_E \parallel R_F \simeq 186 \Omega$$

$$R_{22} \triangleq \left. \frac{v_2}{i_2} \right|_{i_1=0} = R_F + R_E = 1420 \Omega$$

$$\delta \triangleq \left. \frac{i_2}{i_1} \right|_{v_2=0} = -\frac{R_E}{R_F + R_E} \simeq -0.155.$$

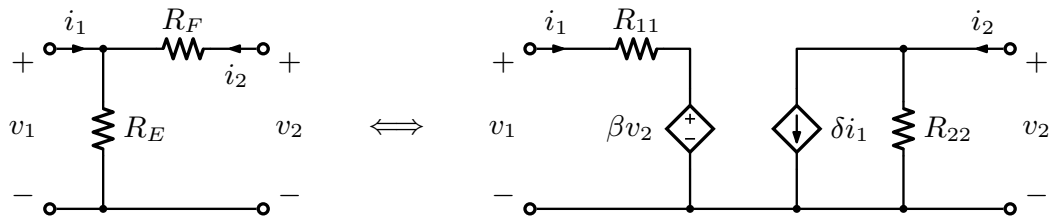


Figure 3: Equivalent β -network model for voltage sampling and voltage mixing.

As usual, the effect of the generator δi_1 is negligible, therefore the β -network can be considered unidirectional. In Figure 4 the β -network is shown separated from the open-loop amplifier.

3. *Closed loop gain* $A_F \triangleq \frac{v_o}{v_s}$.

Since the circuit is a voltage amplifier according to feedback theory, the closed-loop voltage gain A_F can be calculated from the open-loop gain A_{OL} as following:

$$A_F = \frac{A_{OL}}{1 + \beta A_{OL}}.$$

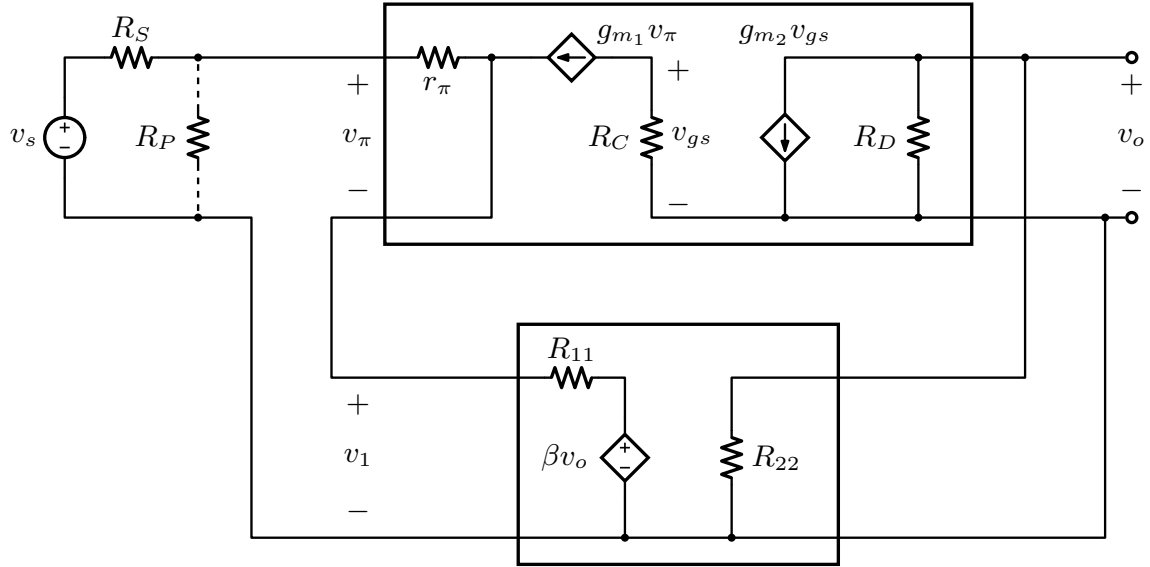


Figure 4: Small signal model according to feedback theory, with the equivalent β -network model separated from the open-loop amplifier and $\delta \approx 0$. R_P is negligible, because $R_P \gg R_S$.

Analysing the two stages of the amplifier, we find the open-loop voltage gain A_{OL} :

$$\begin{aligned}
 A_{OL} &\triangleq \left. \frac{v_o}{v_s} \right|_{\beta=0} = \frac{R_{in}^{CE}}{R_s + R_{in}^{CE}} \cdot \overbrace{\left[-g_{m1} R_C \frac{r_{\pi}}{r_{\pi} + R_{11}(\beta_0 + 1)} \right]}^{A_v^{CE}} \cdot \overbrace{\left[-g_{m2} (R_D \parallel R_{22}) \right]}^{A_v^{CS}} = \\
 &= \frac{r_{\pi} \cdot g_{m1} R_C \cdot g_{m2} (R_D \parallel R_{22})}{R_s + r_{\pi} + R_{11}(\beta_0 + 1)} = \frac{100 \cdot 10 \text{ k}\Omega \cdot 416 \text{ }\mu\text{S} \cdot (2.2 \text{ k}\Omega \parallel 1.42 \text{ k}\Omega)}{1 \text{ k}\Omega + 2812 \text{ }\Omega + 186 \text{ }\Omega \cdot 101} \simeq 15.89
 \end{aligned}$$

Therefore,

$$A_F = \frac{A_{OL}}{1 + \beta A_{OL}} = \frac{15.89}{1 + 0.155 \cdot 15.89} \simeq 4.59.$$

4. Input resistance R_{in} .

The open-loop input resistance is

$$R_{in}^{OL} = R_S + R_{in}^{CE} = R_S + r_{\pi} + R_{11}(\beta_0 + 1) \simeq 22.6 \text{ k}\Omega,$$

where R_{in}^{CE} is the input resistance of the common emitter stage; therefore,

$$R_{in} = R_{in}^{OL} (1 + \beta A_{OL}) - R_S = 22.6 \text{ k}\Omega \cdot (1 + 0.155 \cdot 15.89) - 1 \text{ k}\Omega \simeq 77.3 \text{ k}\Omega.$$

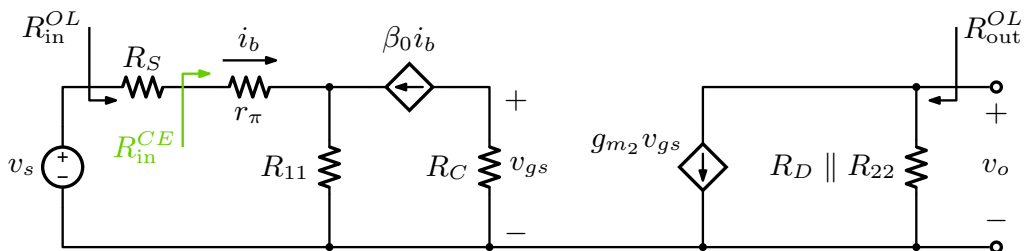
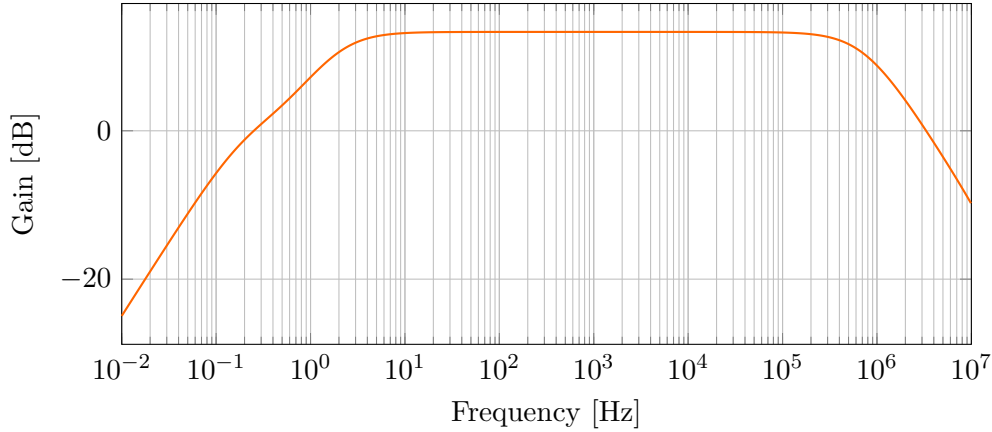


Figure 5: Open-loop small signal model of the amplifier, including loading effects of the β -network.

Figure 6: Simulated AC gain.

5. Output resistance R_{out} .

From inspection, the open-loop output resistance is $R_{\text{out}}^{\text{OL}} = R_D \parallel R_{22} = 863 \Omega$; therefore,

$$R_{\text{out}} = R_{\text{out}}^F = \frac{R_{\text{out}}^{\text{OL}}}{1 + \beta A_{\text{OL}}} = \frac{863 \Omega}{1 + 0.155 \cdot 15.89} \simeq 249 \Omega.$$

6. Estimation of the lower cut-off frequency f_L , under the dominant pole assumption at low frequency.

Using the SCTC method,

$$\omega_L \approx \frac{1}{R_S^{\text{SC}} C_S} + \frac{1}{R_F^{\text{SC}} C_F}$$

where R_S^{SC} is the resistance seen from C_S when C_F is short-circuited, and R_F^{SC} is the resistance seen from C_F when C_S is shorted:

$$R_S^{\text{SC}} = R_{\text{in}}^{\text{OL}} \simeq 22.6 \text{ k}\Omega$$

$$R_F^{\text{SC}} = R_F + R_{\text{out}}^{\text{OL}} + R_E \parallel R_{\text{out}}^{\text{CC}} \simeq 2.1 \text{ k}\Omega, \quad \text{where } R_{\text{out}}^{\text{CC}} = \frac{r_\pi + R_S}{\beta_0 + 1}.$$

Therefore,

$$f_L^{\text{OL}} \approx \frac{1}{2\pi} \left(\frac{1}{R_S^{\text{SC}} C_S} + \frac{1}{R_F^{\text{SC}} C_F} \right) \simeq 7.04 \text{ Hz} + 0.34 \text{ Hz} = 7.38 \text{ Hz}$$

and the closed-loop lower frequency is

$$f_L^{\text{CL}} = \frac{f_L^{\text{OL}}}{1 + \beta A_{\text{OL}}} = \frac{7.38 \text{ Hz}}{1 + 0.155 \cdot 15.89} \simeq 2.13 \text{ Hz},$$

while simulation provides 1.85 Hz, because we assumed a dominant low-frequency pole, but from the Bode diagram in Figure 6 this is not completely verified.